FAIRCHILD
SEMICONDUCTOR®

November 2007

MOC8021M, MOC8050M
Photodarlington Optocoupler (No Base Connection)

Features

- High BV_{CEO}
  - Minimum 50V (MOC8021M)
  - Minimum 80V (MOC8050M)
- High current transfer ratio:
  - Minimum 1,000% (MOC8021M)
  - Minimum 500% (MOC8050M)
- 500%
- No base connection for improved noise immunity
- Underwriters Laboratory (UL) recognized
  File #E90700, Volume 2
- IEC 60747-5-2 approved (ordering option V)

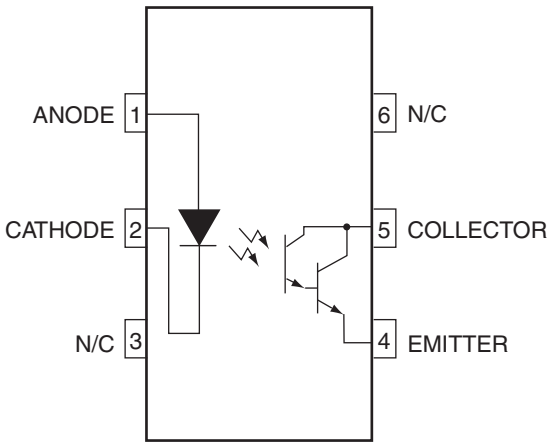
Applications

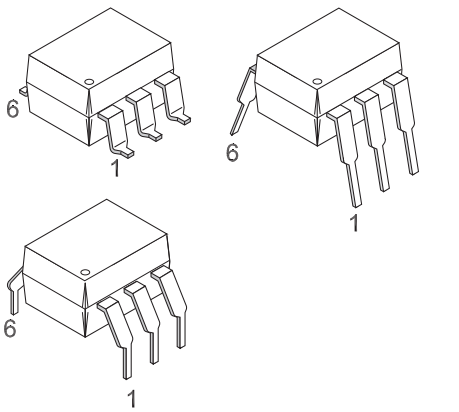
- Appliances, measuring instruments
- I/O interface for computers
- Programmable controllers
- Portable electronics
- Interfacing and coupling systems of different potentials and impedance
- Solid state relays

Description

The MOC8021M and MOC8050M are photodarlington-type optically coupled optocoupler. The devices have a gallium arsenide infrared emitting diode coupled with a silicon darlington phototransistor.

Schematic





Absolute Maximum Ratings (T_A = 25°C Unless otherwise specified.)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Units
TOTAL DEVICE			
T_{STG}	Storage Temperature	-55 to +150	°C
T_{OPR}	Operating Temperature	-40 to +100	°C
T_{SOL}	Lead Solder Temperature (Wave solder)	260 for 10 sec	°C
P_D	Total Device Power Dissipation @ T_A = 25°C	250	mW
	Derate above 25°C	2.94	mW/°C
EMITTER			
I_F	DC/Average Forward Input Current	60	mA
V_R	Reverse Input Voltage	3	V
P_D	LED Power Dissipation @ T_A = 25°C	120	mW
	Derate above 25°C	1.41	mW/°C
DETECTOR			
V_{CEO}	Collector-Emitter Voltage MOC8021M MOC8050M	 50 80	V
P_D	Detector Power Dissipation @ T_A = 25°C	150	mW
	Derate above 25°C	1.76	mW/°C
I_C	Continuous Collector Current	150	mA

Electrical Characteristics (T_A = 25°C Unless otherwise specified.)

Individual Component Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.*	Max.	Unit
EMITTER						
V_F	Input Forward Voltage	I_F = 10mA		1.18	2.00	V
I_R	Reverse Leakage Current	V_R = 3.0V		0.001	10	µA
DETECTOR						
BV_{CEO}	Collector-Emitter Breakdown Voltage MOC8021M MOC8050M	I_C = 1.0mA, I_F = 0	 50 80	 100 100		V
BV_{ECO}	Emitter-Collector Breakdown Voltage	I_E = 100µA, I_F = 0	5	10		V
I_{CEO}	Collector-Emitter Dark Current	V_{CE} = 60V, I_F = 0			1	µA
C_{CE}	Capacitance	V_{CE} = 0V, f = 1MHz		8		pF

Transfer Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.*	Max.	Unit
DC CHARACTERISTICS						
CTR	Current Transfer Ratio, Collector to Emitter MOC8021M MOC8050M	 I_F = 10mA, V_{CE} = 5V I_F = 10mA, V_{CE} = 1.5V	 1,000 500			%
AC CHARACTERISTICS						
t_{on}	Non-Saturated Turn-on Time	I_F = 5mA, V_{CC} = 10V, R_L = 100Ω		8.5		µs
t_{off}	Turn-off Time	I_F = 5mA, V_{CC} = 10V, R_L = 100Ω		95		µs

Isolation Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Units
V_{ISO}	Input-Output Isolation Voltage	f = 60Hz, t = 1 sec.	7500			Vac(pk)
R_{ISO}	Isolation Resistance	V_{I-O} = 500VDC	10^{11}			Ω
C_{ISO}	Isolation Capacitance	V_{I-O} = Ø, f = 1MHz		0.2	2	pF

Note:
*Typical values at T_A = 25°C

Typical Performance Curves

Fig. 1 LED Forward Voltage vs. Forward Current

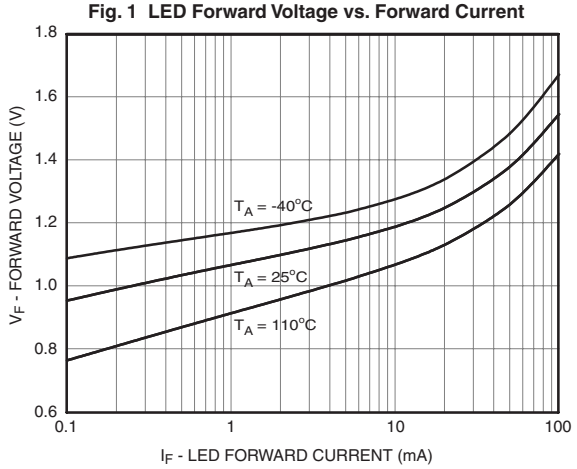


Fig. 2 Normalized CTR vs. Forward Current

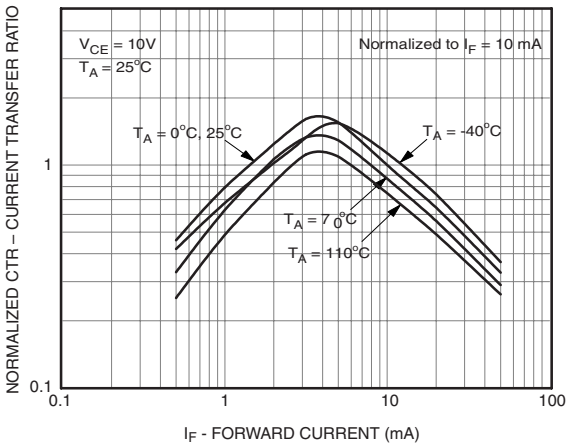


Fig. 3 Normalized CTR vs. Ambient Temperature

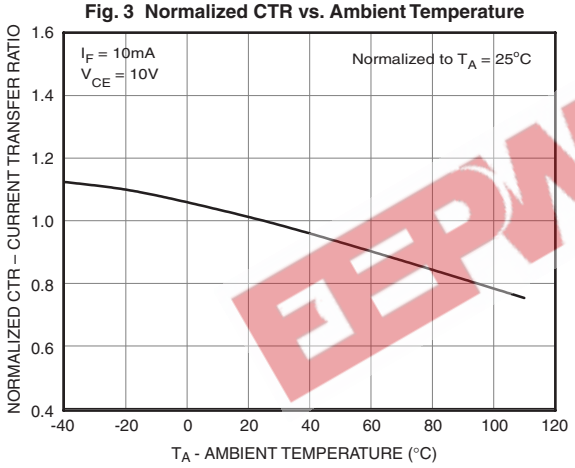


Fig. 4 Turn-on Time vs. Forward Current

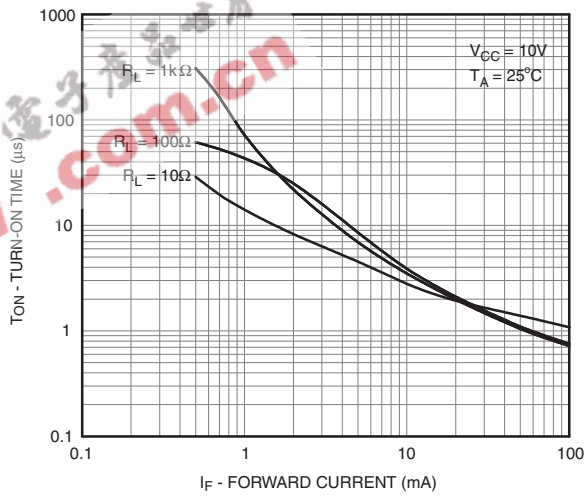


Fig. 5 Turn-off Time vs. Forward Current

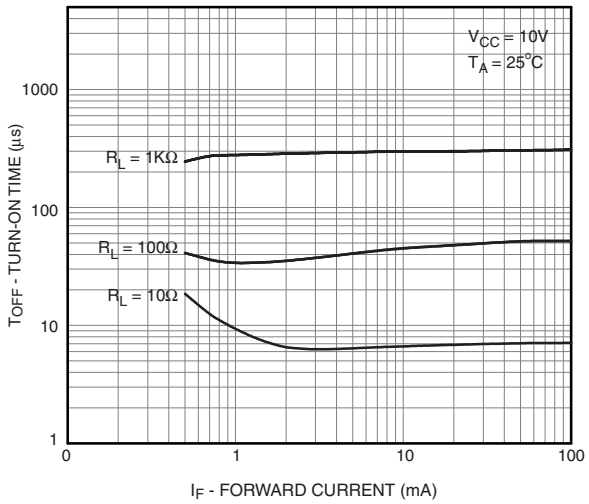
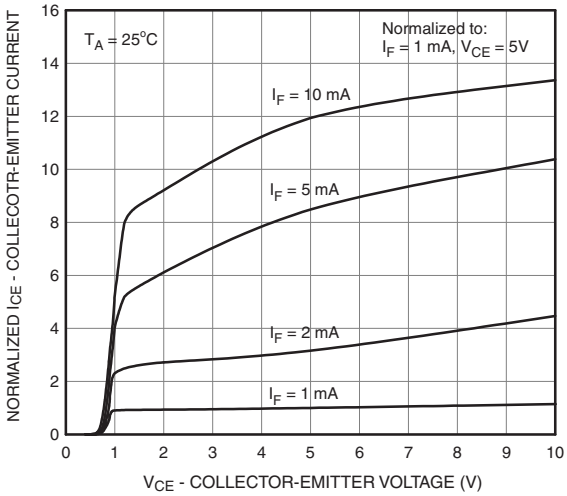
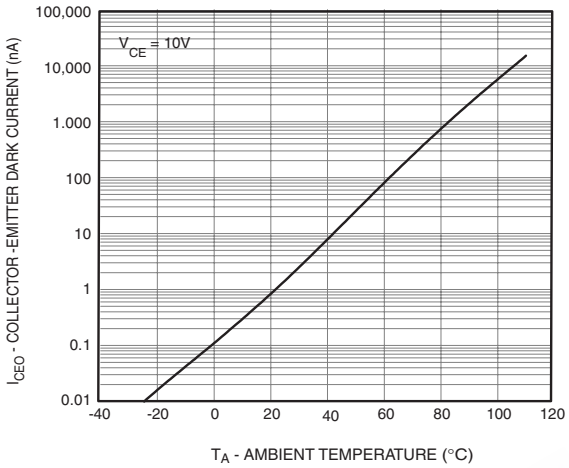


Fig. 6 Normalized Collector-Emitter Current vs. Collector-Emitter Voltage



Typical Performance Curves (Continued)

Fig. 7 Dark Current vs. Ambient Temperature



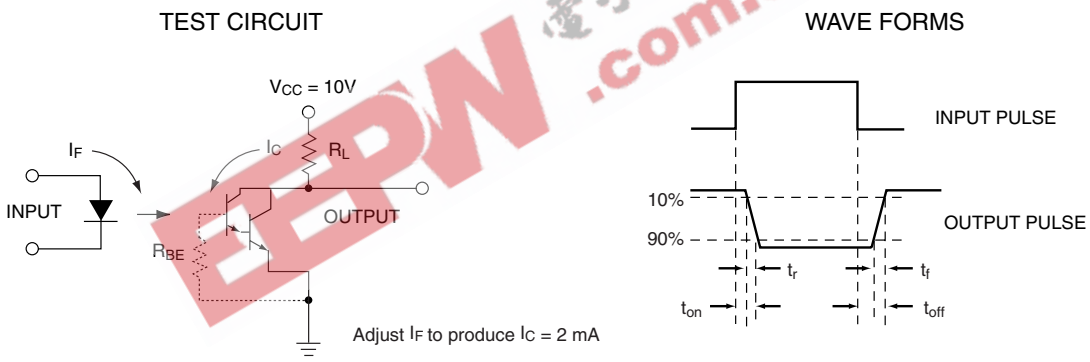
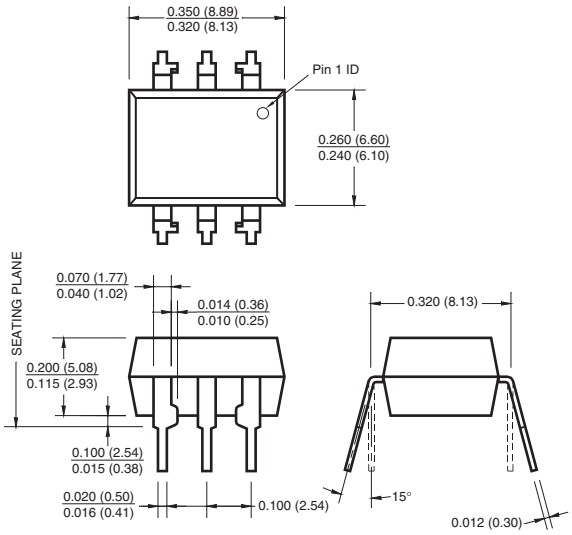


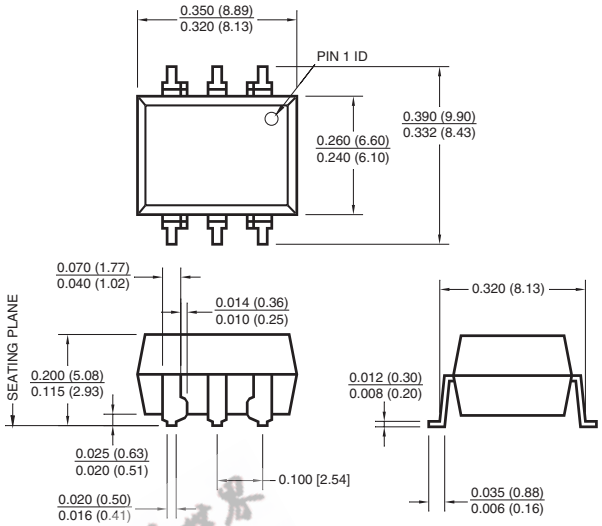
Figure 8. Switching Time Test Circuit and Waveforms

Package Dimensions

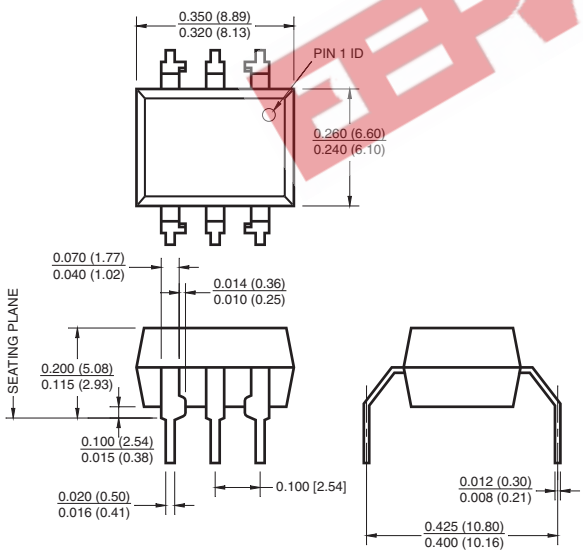
Through Hole



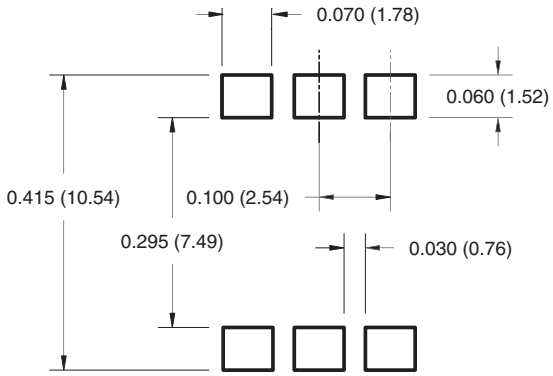
Surface Mount



0.4" Lead Spacing



Recommended Pad Layout for Surface Mount Leadform

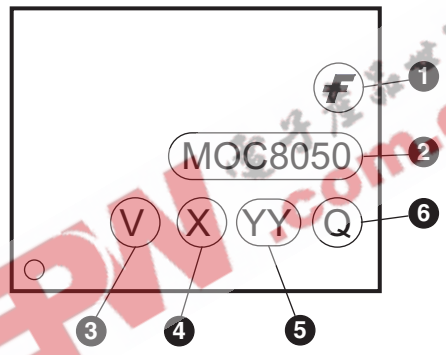


Note:
All dimensions are in inches (millimeters).

Ordering Information

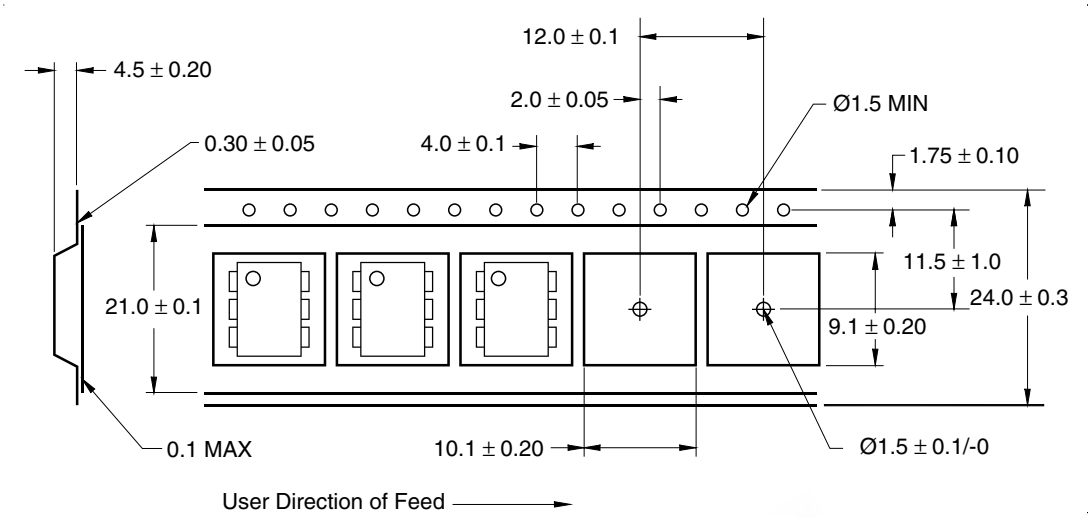
Option	Order Entry Identifier (Example)	Description
No suffix	MOC8050M	Standard Through Hole Device (50 parts per tube)
S	MOC8050SM	Surface Mount Lead Bend
SR2	MOC8050SR2M	Surface Mount; Tape and Reel
T	MOC8050TM	0.4" Lead Spacing
V	MOC8050VM	IEC60747-5-2
TV	MOC8050TVM	IEC60747-5-2, 0.4" Lead Spacing
SV	MOC8050SVM	IEC60747-5-2, Surface Mount
SR2V	MOC8050SR2VM	IEC60747-5-2, Surface Mount, Tape and Reel

Marking Information



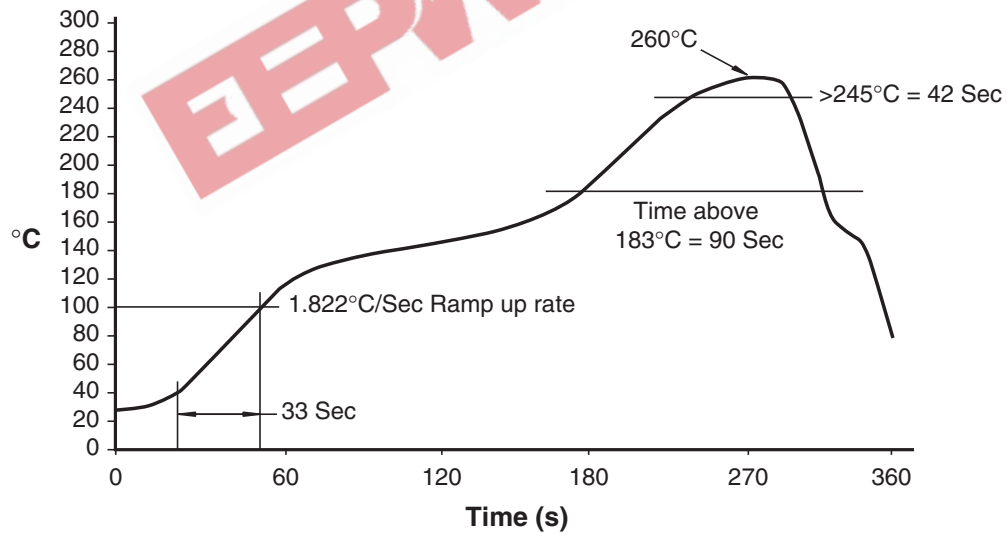
Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code, e.g., ‘7’
5	Two digit work week ranging from ‘01’ to ‘53’
6	Assembly package code

Tape Dimensions



Note:
All dimensions are in millimeters.

Reflow Soldering Profile



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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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Rev. I31